

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

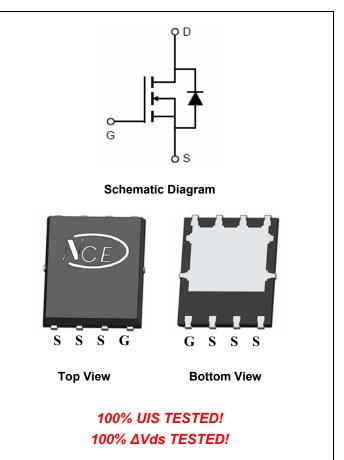
The NCEP01T10G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- $V_{DS}$  =100V, $I_D$  =105A  $R_{DS(ON)}$ =5.6m $\Omega$  (typical) @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150°C operating temperature
- Pb-free lead plating
- 100% UIS tested

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP01T10G	NCEP01T10G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	105	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	74	Α
Pulsed Drain Current	I <sub>DM</sub>	400	А
Maximum Power Dissipation	P <sub>D</sub>	135	W
Derating factor		1.1	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	676	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2) R <sub>0JC</sub> 0.93 °C/W
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# Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			1			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>					•
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	2.5	-	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =50A	-	5.6	6.4	mΩ
Forward Transconductance	<b>g</b> Fs	V <sub>DS</sub> =10V,I <sub>D</sub> =50A	40	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	4300	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	-	790	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	Γ-1.UIVIΠZ	-	47	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	13	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50V, $I_D$ =50A $V_{GS}$ =10V, $R_G$ =4.7 $\Omega$	-	58	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	39	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	8	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =50V,I <sub>D</sub> =50A,	-	60		nC
Gate-Source Charge	Q <sub>gs</sub>		-	21		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	11		nC
Drain-Source Diode Characteristics	<u> </u>					•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =50A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	105	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25$ °C, $I_F = I_S$	-	60		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	140		nC

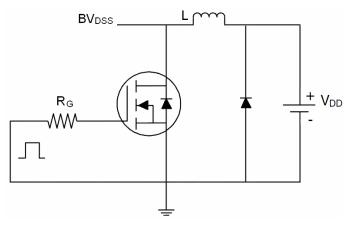
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\!\!\mathrm{C}$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

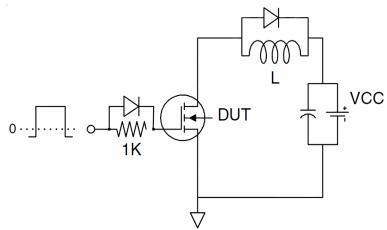


### **Test Circuit**

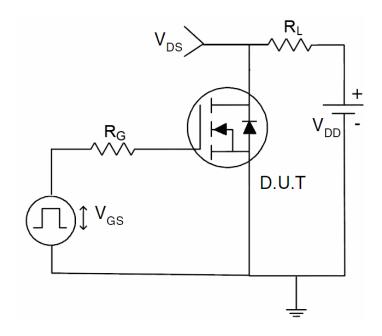
# 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit

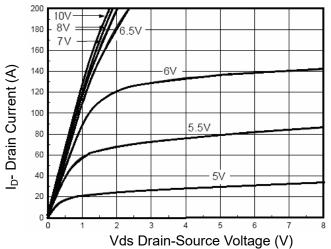


## 3) Switch Time Test Circuit

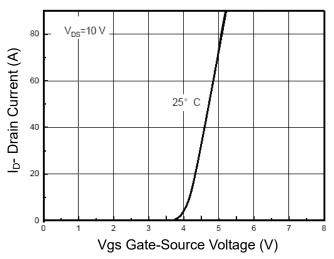




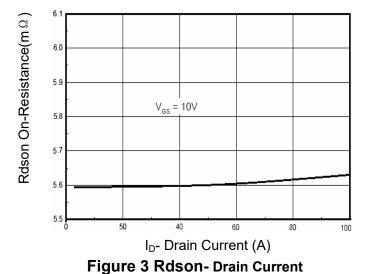
### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



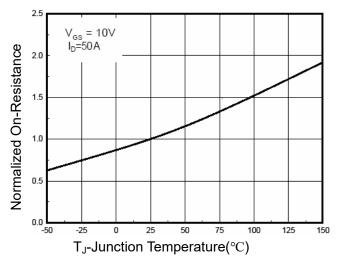


Figure 4 Rdson-JunctionTemperature

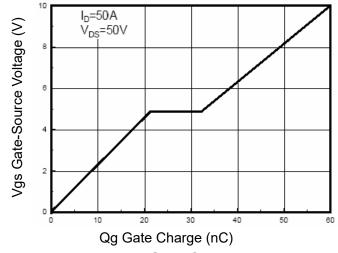


Figure 5 Gate Charge

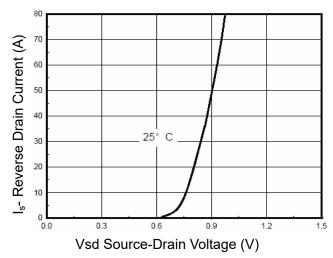
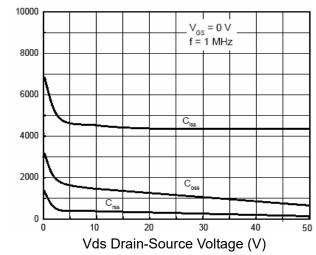


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)



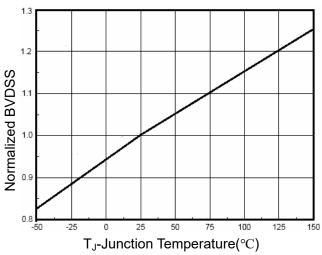
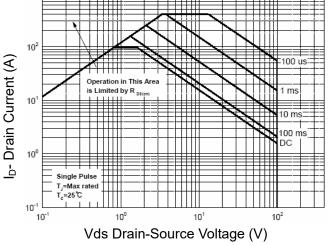
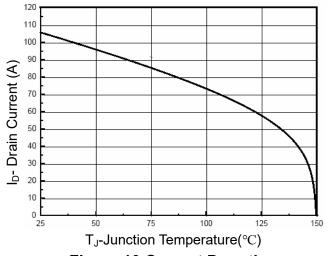


Figure 7 Capacitance vs Vds Figure

Figure 9 BV<sub>DSS</sub> vs Junction Temperature





**Figure 8 Safe Operation Area** 

Figure 10 Current De-rating

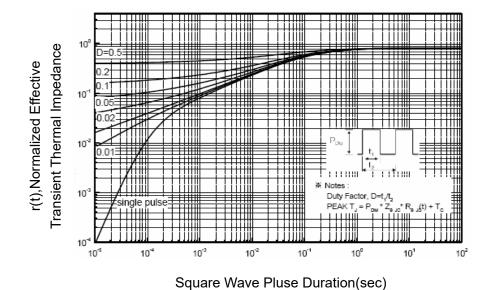
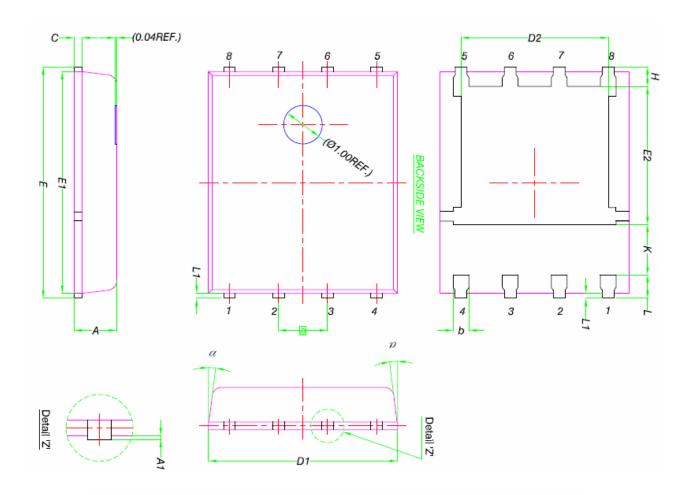


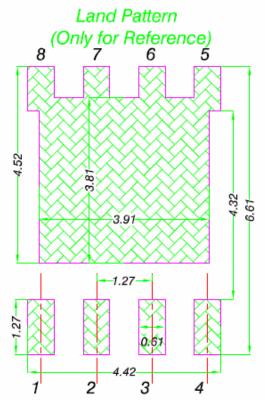
Figure 11 Normalized Maximum Transient Thermal Impedance



# **DFN5X6-8L Package Information**



5.07	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
Α	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е		1.27 BSC			
Н	0.41	0.51	0.61		
K	1.10	-	-		
L	0.51	0.61	0.71		
L1	0.06	0.13	0.20		
α	O°	-	12°		





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